

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE6005AS uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

V_{DS}=60V,I_D=5A

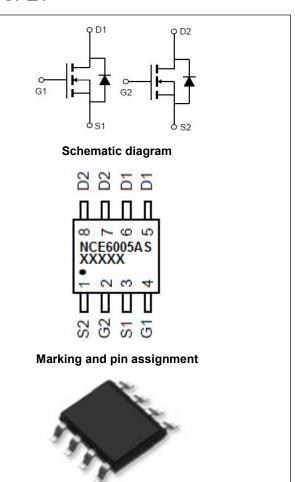
 $R_{DS(ON)}$ <30m Ω @ V_{GS} =10V (Typ.26m Ω)

 $R_{DS(ON)}$ <38m Ω @ V_{GS} =4.5V (Typ.32m Ω)

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



SOP-8 top view

Package Marking and Ordering Information

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Device Marking		Device	Device Package	Reel Size	Tape width	Quantity
	NCE6005AS	NCE6005AS	SOP-8	Ø330mm	12mm	4000 units

Absolute Maximum Ratings (T_A=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	60	V
Gate-Source Voltage	V _G s	±20	V
Drain Current-Continuous	I _D	5	Α
Drain Current-Continuous(T _C =100℃)	I _D (100°C)	3.5	Α
Pulsed Drain Current	I _{DM}	24	Α
Maximum Power Dissipation	P _D	2	W
Single pulse avalanche energy (Note 5)	E _{AS}	65	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	62.5	°C/W
	00/1	1	



Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	·					
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	60	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.2	1.6	2.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =5A	-	26	30	mΩ
Drain-Source On-State Resistance	own Voltage BV _{DSS} V _{GS} =0V I _D =250μA rain Current I _{DSS} V _{DS} =60V,V _{GS} =0V Current I _{GSS} V _{GS} =±20V,V _{DS} =0V Note 3) V _{DS} =±250μA I _{DS} (ON) V _{DS} =10V, I _D =5A I _{DS} (ON) V _{DS} =30V, I _D =5A I _{DS} (ON) V _{DS} =5V, I _D =5A I _{DS} (ON) V _{DS} =5V, I _D =5A I _{DS} (ON) V _{DS} =30V,V _{GS} =0V, I _D =5A I _{DS} (ON) V _{DS} =30V,V _{GS} =0V, I _D =5A I _{DS} (ON) V _{DS} =30V,V _{DS} =3Q I _D (I _D (I _D) V _D I _D =3QV, I _D =5A, I _D =5A, I _D =5A I _D (I _D (I _D) V _D I _D =3QV,I _D =5A, I _D =5A, I _D =5A I _D (I _D (I _D) V _D I _D =3QV,I _D =5A, I _D =5A I _D (I _D (I _D) V _D I _D =5A, I _D =5A I _D (I _D (I _D) V _D I _D =5A I _D (I _D (I _D) V _D I _D =5A I _D (I _D (I _D) V _D I _D =5A I _D (I _D (I _D) V _D I _D =5A I _D (I _D (I _D) V _D I _D =5A I _D (I _D (I _D) V _D I _D =5A I _D (I _D (I _D) V _D I _D =5A I _D (I _D (I _D) V _D I _D =5A	-	32	38	mΩ	
Forward Transconductance	g FS	V _{DS} =5V,I _D =5A	11	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	N/ 00\/N/ 0\/	-	846	-	PF
Output Capacitance	Coss	, , , , ,	-	65	-	PF
Reverse Transfer Capacitance	C _{rss}		-	61.8	-	PF
Switching Characteristics (Note 4)			'			
Turn-on Delay Time	t _{d(on)}		-	5.2	-	nS
Turn-on Rise Time	tr	V _{DD} =30V, R _L =6.7Ω	-	3	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =3 Ω	-	17	-	nS
Turn-Off Fall Time	t _f		-	2.5	-	nS
Total Gate Charge	Qg	\/ 00\/ 54	-	25		nC
Gate-Source Charge	Qgs		-	3		nC
Gate-Drain Charge	Q _{gd}		-	6.4		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =5A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	5	Α
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is neg	ligible (tur	n-on is do	ominated b	y LS+LD

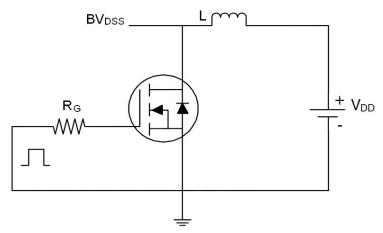
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300μ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition:Tj=25 $^{\circ}\text{C}$,VDD=30V,VG=10V,L=0.5mH,Rg=25 Ω

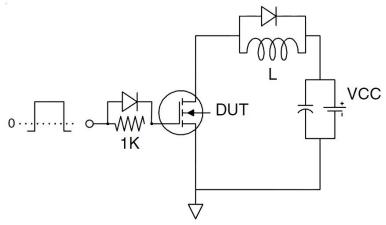


Test Circuit

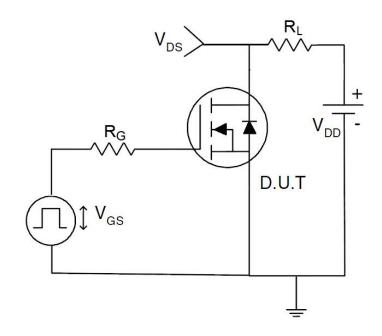
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

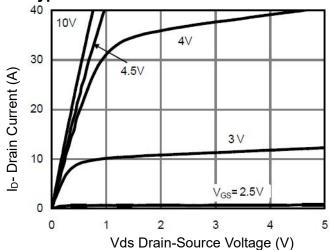


Figure 1 Output Characteristics

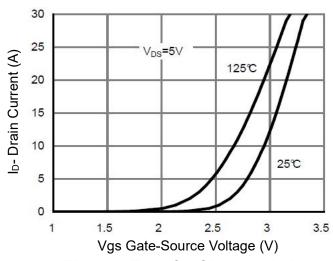


Figure 2 Transfer Characteristics

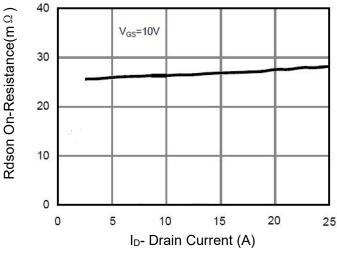


Figure 3 Rdson- Drain Current

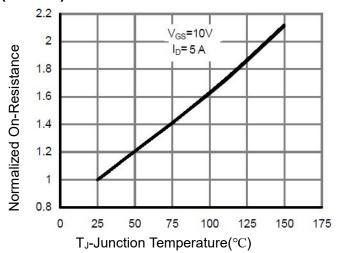


Figure 4 Rdson-Junction Temperature

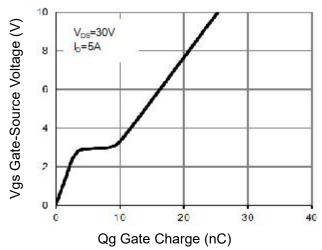


Figure 5 Gate Charge

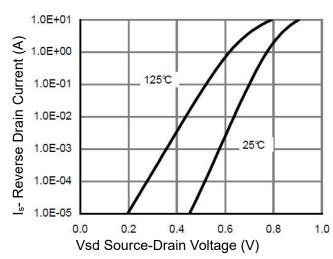
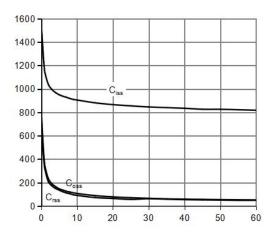


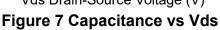
Figure 6 Source- Drain Diode Forward







Vds Drain-Source Voltage (V)



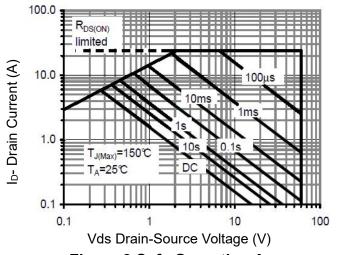


Figure 8 Safe Operation Area

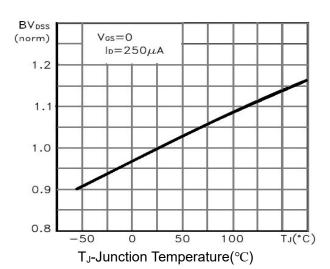


Figure 9 BV_{DSS} vs Junction Temperature

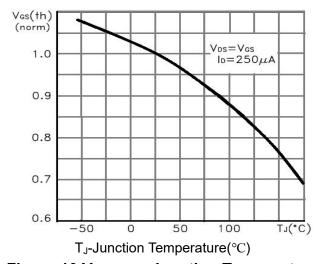


Figure 10 V_{GS(th)} vs Junction Temperature

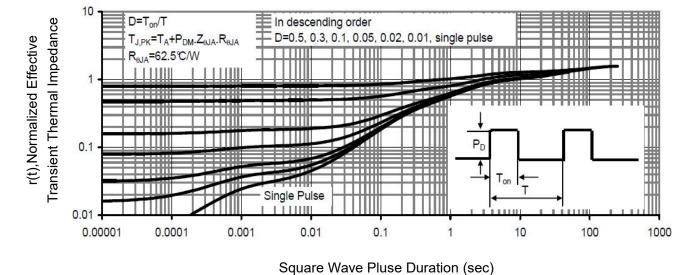
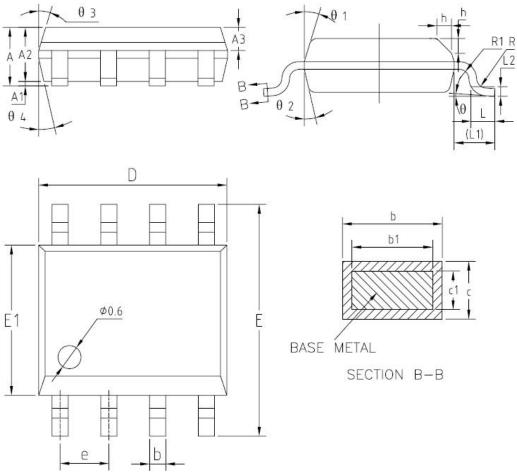


Figure 11 Normalized Maximum Transient Thermal Impedance



SOP-8 Package Information



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX		
Α	1.35	1.55	1.75		
A1	0.10	0.15	0.25		
A2	1.25	1.40	1.65		
A3	0.50	0.60	0.70		
b	0.38	-	0.51		
b1	0.37	0.42	0.47		
С	0.18	_	0.25		
c1	0.17	0.20	0.23		
D	4.80	4.90	5.00		
E	5.80	6.00	6.20		
E1	3.80	3.90	4.00		
e	1.17	1.27	1.37		
L	0.45	0.60	0.80		
L1		1.04REF			
L2					
R	0.07	_	100		
R1	0.07	_	-		
h	0.30	0.40	0.50		
θ	0,	-	8"		
θ 1	15*	17*	19*		
92	11"	13°	15*		
03	15*	17	19*		
θ 4	11'	13*	15*		

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